MSD42WT1G, NSVMSD42WT1G

NPN High Voltage Transistors

This NPN Silicon Planar Transistor is designed for general purpose amplifier applications. This device is housed in the SC-70/SOT-323 package which is designed for low power surface mount applications.

Features

- These Devices are Pb-Free, Halogen Free and are RoHS Compliant
- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable

MAXIMUM RATINGS $(T_A = 25^{\circ}C)$

Rating	Symbol	Value	Unit
Collector-Base Voltage	V _{(BR)CBO}	300	V
Collector-Emitter Voltage	V _{(BR)CEO}	300	V
Emitter-Base Voltage	V _{(BR)EBO}	6.0	V
Collector Current - Continuous	Ic	150	mA

THERMAL CHARACTERISTICS

Rating	Symbol	Max	Unit
Power Dissipation (Note 1)	P _D	450	mW
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{ heta JA}$	274	°C/W
Junction and Storage Temperature Range	T _J , T _{stg}	-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

ELECTRICAL CHARACTERISTICS

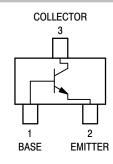
Characteristic	Symbol	Min	Max	Unit
Collector-Emitter Breakdown Voltage $(I_C = 1.0 \text{ mA}, I_B = 0)$	V _{(BR)CEO}	300	-	V
Collector-Base Breakdown Voltage ($I_C = 100 \mu A, I_E = 0$)	V _{(BR)CBO}	300	-	V
Emitter-Base Breakdown Voltage ($I_E = 100 \mu A, I_E = 0$)	V _{(BR)EBO}	6.0	-	V
Collector-Base Cutoff Current (V _{CB} = 200 V, I _E = 0)	I _{CBO}	-	0.1	μΑ
Emitter-Base Cutoff Current (V _{EB} = 6.0 V, I _B = 0)	I _{EBO}	-	0.1	μΑ
DC Current Gain (Note 2) $(V_{CE} = 10 \text{ V, I}_{C} = 1.0 \text{ mA})$ $(V_{CE} = 10 \text{ V, I}_{C} = 30 \text{ mA})$	h _{FE1}	25 40	- -	-
Collector-Emitter Saturation Voltage (Note 2) (I _C = 20 mA, I _B = 2.0 mA)	V _{CE(sat)}	-	0.5	V

- 1. FR-4 @ 10 mm², 1 oz. Copper traces.
- 2. Pulse Test: Pulse Width \leq 300 µs, D.C. \leq 2%.



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SC-70 (SOT-323) CASE 419 STYLE 3

MARKING DIAGRAM



1D = Specific Device Code

M = Date Code

■ = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
MSD42WT1G	SC-70 (Pb-Free)	3000 / Tape & Reel
NSVMSD42WT1G	SC-70 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MSD42WT1G, NSVMSD42WT1G

TYPICAL CHARACTERISTICS

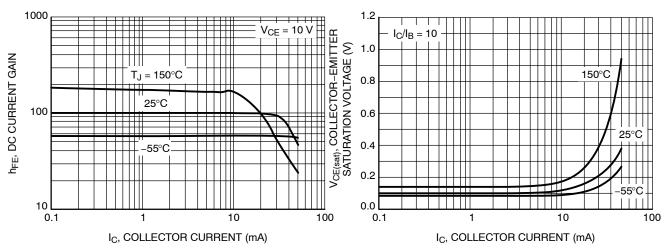


Figure 1. DC Current Gain

Figure 2. Collector-Emitter Saturation Voltage vs. Collector Current

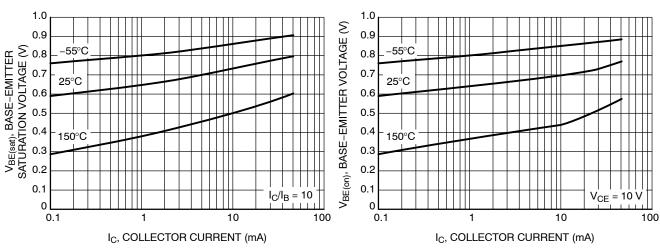


Figure 3. Base-Emitter Saturation Voltage vs.
Collector Current

Figure 4. Base–Emitter On Voltage vs.
Collector Current

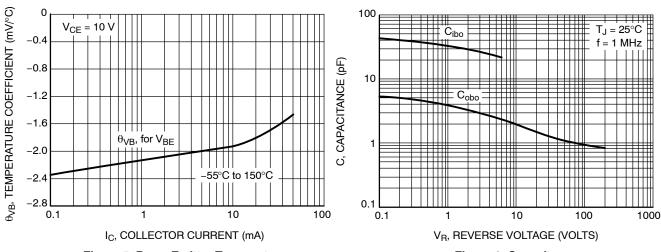
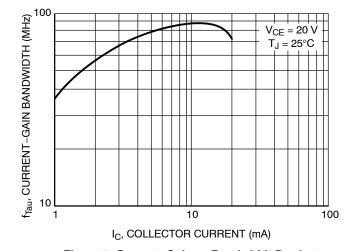


Figure 5. Base–Emitter Temperature Coefficient

Figure 6. Capacitance

MSD42WT1G, NSVMSD42WT1G

TYPICAL CHARACTERISTICS



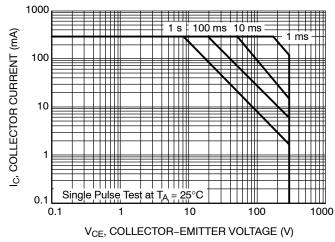
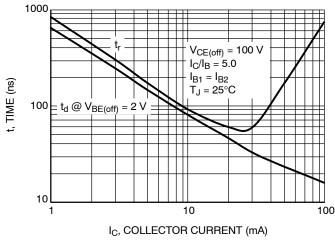


Figure 7. Current-Gain — Bandwidth Product

Figure 8. Safe Operating Area



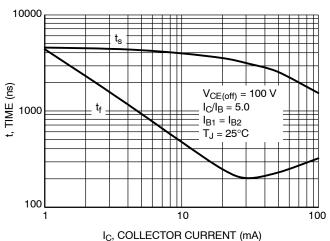


Figure 9. Turn-On Time

Figure 10. Turn-Off Time





SC-70 (SOT-323) **CASE 419** ISSUE R

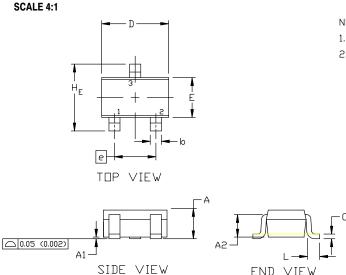
END VIEW

DATE 11 OCT 2022

NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH

	MILLIMETERS			INCHES			
DIM	MIN.	N□M.	MAX.	MIN.	N□M.	MAX.	
Α	0.80	0.90	1.00	0.032	0.035	0.040	
A1	0.00	0.05	0.10	0.000	0.002	0.004	
A2		0.70 REF	-		0.028 BSC		
b	0.30	0.35	0.40	0.012	0.014	0.016	
C	0.10	0.18	0.25	0.004	0.007	0.010	
D	1.80	2.00	2.20	0.071	0.080	0.087	
E	1.15	1.24	1.35	0.045	0.049	0.053	
е	1.20	1.30	1.40	0.047	0.051	0.055	
e1	0.65 BSC			0.026 BS	C		
L	0.20	0.38	0.56	0.008	0.015	0.022	
HE	2.00	2.10	2.40	0.079	0.083	0.095	



GENERIC MARKING DIAGRAM

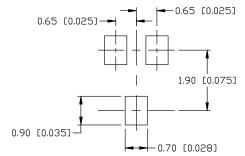


= Specific Device Code XX

Μ = Date Code

= Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.



For additional information on our Pb-Free strategy and soldering details, please download the ID Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

SOLDERING FOOTPRINT

STYLE 1: CANCELLED	STYLE 2: PIN 1. ANODE 2. N.C. 3. CATHODE	STYLE 3: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 4: PIN 1. CATHODE 2. CATHODE 3. ANODE	STYLE 5: PIN 1. ANODE 2. ANODE 3. CATHODE	
STYLE 6: PIN 1. EMITTER	STYLE 7: PIN 1. BASE	STYLE 8: PIN 1. GATE	STYLE 9: PIN 1. ANODE	STYLE 10: PIN 1. CATHODE	STYLE 11: PIN 1. CATHODE
2. BASE	2. EMITTER	2. SOURCE	2. CATHODE	2. ANODE	2. CATHODE
COLLECTOR	COLLECTOR	3. DRAIN	CATHODE-ANODE	3. ANODE-CATHODE	CATHODE

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DESCRIPTION:	SC-70 (SOT-323)		PAGE 1 OF 1

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